

# HIGH POWER SEMICONDUCTOR DEVICE PRODUCT CATALOGUE

## 大功率半导体器件



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## 公司简介

江苏扬杰润奥半导体有限公司是扬州扬杰电子科技股份有限公司旗下大功率半导体器件的生产基地。公司持续引进和采用先进的制造和生产技术，为全球客户设计、研发、检测和制造大功率晶闸管、整流管、功率模块和功率组件等。

凭借不断的发展和前沿技术的应用，产品广泛应用于电力牵引、输变电、轧钢、感应加热、电解电镀、焊机、变频器、软起动器、电动机调速器、UPS、SVC 以及家用电器等。

公司具有快速响应，持续改进的优良品质。并致力于让世界信赖中国功率半导体。



Jiangsu Yangjie Runau Semiconductor Co., Ltd. is the professional manufacturer of high power semiconductor devices as a company of Yangzhou Yangjie Electronic Technology Co., Ltd. The company continues to introduce and apply advanced manufacturing technologies as well as design, develop, inspect and produce high power thyristor, rectifier, power module and power assembly unit for global customers.

With ongoing development and application of cutting-edge skills, the company products are widely used in electric traction, power transmission and transformation, steel rolling, induction heating, electrolytic plating, welding machines, frequency converters, soft starters, motor speed regulators, UPS, SVC and household appliances ...etc.

The company advantages in the virtues of fast response and continuous improvement to commit the mission that let the world trust China's power semiconductors.

**2000**

成立  
江苏扬杰电子有限公司

**2006**

设立桥堆二极管产线

**2009**

设立4寸芯片产线

**2012**

IPO成功过会  
通过TS16949认证  
设立功率模块产线

**2013**

设立4寸芯片第二条产线  
大规模自动化设备取代手工  
Philips认证

**2021**

收购江苏润奥

**2019**

日本办事处成立

**2018**

设立汽车电子  
产线收购宜兴  
杰芯高压MOS产  
线，持有51%股份

**2017**

设立  
小信号产线

**2016**

设立6寸  
SKY芯片产线  
成立  
低压MOS研发中心

**2014**

“300373”成功登陆深交所  
台湾办事处成立  
通过Delta认证

**2015**

设立DFN QFN产线  
美国分公司成立  
韩国办事处成立



**参数文字符号一览表**  
SYMBOL TABLE

**产品命名规则 PRODUCT NAME RULES**

产品类型 Product Type	参数符号 Parameter symbol	参数名称 Description	参数名称 Description
整流管 DIODE	V <sub>RRM</sub>	反向重复峰值电压	Repetitive peak reverse voltage
	V <sub>FM</sub>	正向峰值电压	Peak forward voltage
	V <sub>F(AV)</sub>	正向平均电压	Mean forward voltage
	V <sub>FO</sub>	门槛电压	Threshold voltage
	I <sub>F(RSM)</sub>	正向方均根电流	Rms forward current
	I <sub>F(AV)</sub>	正向平均电流	Mean forward current
	I <sub>FMS</sub>	浪涌电流	Surge forward current
	I <sub>RRM</sub>	反向重复峰值电流	Repetitive peak reverse current
	I <sub>RR(AV)</sub>	反向重复平均电流	Repetitive mean reverse current
	I <sup>2</sup> t	I <sup>2</sup> t	I squared t
	T <sub>j</sub>	工作结温	Operating junction temperature
	T <sub>stg</sub>	贮存温度	Storage temperature
	Q <sub>rr</sub>	恢复电荷	Recovery charge
	t <sub>rr</sub>	反向恢复时间	Reverse recovery time
	R <sub>jc</sub>	结亮热阻	Thermal resistance junction-case
	r <sub>FO</sub>	正向斜率电阻	Forward slope resistance
	I <sub>RRM</sub>	反向重复峰值电流	Repetitive peak reverse current
	I <sub>RR(AV)</sub>	反向重复平均电流	Repetitive mean reverse current
	I <sub>GT</sub>	门极触发电流	Gate trigger current
	I <sub>H</sub>	维持电流	Holding current
	I <sub>GM</sub>	门极峰值电流	Peak gate current
	I <sup>2</sup> t	I <sup>2</sup> t	I squared t
	P <sub>GM</sub>	门极峰值功率	Peak gate power
	P <sub>G(AV)</sub>	门极平均功率	Mean gate power
	T <sub>j</sub>	工作结温	Operating junction temperature
	tgt	门极控制开通时间	Gate-controlled turn-on time
	tq	电路换向关断时间	Circuit-commutated turn-off time
	dv/dt	断态电压临界上升率	Critical rise rate of off-state voltage
晶闸管 THYRISTOR	r <sub>TO</sub>	通态斜率电阻	On-state slope resistance
	T <sub>stg</sub>	贮存温度	Storage temperature
	V <sub>RRM</sub>	反向重复峰值电压	Repetitive peak reverse voltage
	V <sub>DRM</sub>	断态重复峰值电压	Repetitive peak off-state voltage
	V <sub>RGM</sub>	门极反向峰值电压	Peak reverse gate voltage
	V <sub>TM</sub>	通态峰值电压	Peak on-state voltage
	V <sub>T(AV)</sub>	通态平均电压	Mean on-stage voltage
	V <sub>GT</sub>	门极触发电压	Gate trigger voltage
	V <sub>GD</sub>	门极不触发电压	Gate non-trigger voltage
	V <sub>TO</sub>	通态门槛电压	On-state threshold voltage
	V <sub>GM</sub>	门极峰值电压	Peak gate voltage
	V <sub>T(RMS)</sub>	通态方均根电压	R.M.S on-state voltage
	I <sub>T(AV)</sub>	通态平均电流	Mean on-state current
	I <sub>T(RMS)</sub>	通态方均根电流	R.M.S on-state current
	I <sub>FGM</sub>	门极正向峰值电流	Forward gate current
	I <sub>DRM</sub>	断态重复峰值电流	Repetitive peak off-state current
	I <sub>DR(AV)</sub>	断态重复平均电流	Repetitive mean off-state current
	I <sub>TSM</sub>	浪涌电流	Surge on-state current

**KP 1000 - \*\***

两个字母代表器件的种类  
The type of the devices  
KP 普通晶闸管Phase Control Thyristor  
KK 快速晶闸管Fast Switching Thyristor  
KA 高频晶闸管High Frequency Thyristor  
KN 逆导晶闸管Reverse Conducting Thyristor  
KS 双向晶闸管Bidirectional Thyristor  
ZP 普通整流管Standard Diode  
ZK 快速整流管Fast Recovery Diode  
ZW 焊接整流管Welding Diode  
ZA 雪崩整流管Avalanche Diode

额定电压级数  
Rated Voltage Level (\*\*x100=V<sub>DRM</sub>/V<sub>RRM</sub>)

额定电流  
Rated Current I<sub>T(AV)</sub>/I<sub>F(AV)</sub>

**TT 200 - \*\***

器件类别Device Type  
TT:双晶闸管Dual Thyristors  
TD: 晶闸管/整流管Thyristor and Diode  
DT:整流管/晶闸管Diode and Thyristor  
DD:双整流管Dual Diodes  
TZ:单晶闸管Single Thyristor  
DZ:单整流管Single Diode

额定电压级数  
Rated Voltage Level (\*\*x100=V<sub>DRM</sub>/V<sub>RRM</sub>)

额定电流  
Rated Current I<sub>T(AV)</sub>/I<sub>F(AV)</sub>

**M T C 90 - \*\***

模块  
Module

器件类别Device Type  
D:普通整流管General Purpose Rectifier  
T:普通晶闸管Phase Control Thyristor  
Z:快速整流管Fast Recovery Rectifier  
K:快速晶闸管Fast Switching Thyristor  
F:D&T H:Z&K

额定电压级数  
Rated Voltage Level (\*\*x100=V<sub>DRM</sub>/V<sub>RRM</sub>)

额定电流  
Rated Current I<sub>T(AV)</sub>/I<sub>F(AV)</sub>

C:串联Series  
K:共阴极Common Cathode  
A:共阳极Common Anode  
Y:三相共阴极Three Phase Common Cathode  
G三相共阳极 Three Phase Common Anode  
X:反并联Antiparallel  
Q:单相桥Single Phase Bridge  
S:三相桥Three Phase Bridge

# CATALOG

## 目录

晶闸管芯片 THYRISTOR CHIPS .....	01
整流管芯片 DIODE CHIPS .....	02
方形晶闸管芯片 SQUARE THYRISTOR CHIPS .....	03
普通晶闸管 PHASE CONTROL THYRISTOR .....	04-06
快速晶闸管 FAST SWITCHING THYRISTOR .....	07-08
逆导晶闸管 REVERSE—CONDUCTING THYRISTOR .....	08
高频晶闸管 HIGH FREQUENCY THYRISTOR .....	09
双向晶闸管 BIDIRECTIONAL THYRISTOR .....	09
晶闸管外形图 OUTLINE OF CAPSULE TYPE THYRISTOR .....	10-11
门极可关断晶闸管 GATE TURN-OFF THYRISTOR .....	12
普通整流管 STANDARD DIODE .....	13-15
雪崩二极管 AVALANCHE DIODE .....	15
快恢复整流管 FAST RECOVERY DIODE .....	16
整流管外形图 OUTLINE OF DIODE .....	17
焊接二极管 WELDING DIODE .....	18
晶闸管模块 THYRISTOR MODULE .....	19-20
整流管模块 DIODE MODULE .....	21-22
晶闸管/整流管混合 THYRISTOR/DIODE MODULE .....	23-24
模块外形图 OUTLINE OF POWER MODULE .....	25-26
散热器及功率组件 HEATSINKS AND POWER ASSEMBLIES .....	27-29

### 晶闸管芯片 THYRISTOR CHIPS

标准:

- ◆每只芯片全部在T<sub>jm</sub>下测试，严格禁止抽检
- ◆产品参数一致性极佳

Standard:

- ◆Every chip is tested at T<sub>jm</sub>, random inspection is strictly prohibited
- ◆Excellent consistency of the chips' parameters

特点:

- ◆通态压降低
- ◆具有很强的抗热疲劳能力
- ◆阴极铝层厚度10微米以上
- ◆台面双层保护
- Features:
- ◆Low forward voltage
- ◆Strong thermal fatigue resistance
- ◆The thickness of cathode aluminum layer is above 10μm
- ◆Double layer protections on mesa



芯片直径 Diameter (mm)	芯片厚度 Thickness (mm)	电压范围 Voltage (v)	门极直径 Gate Dia. (mm)	阴极内径 Cathode Inner Dia. (mm)	阴极外径 Cathode Outer Dia. (mm)	结温 T <sub>jm</sub> (C)
25.4	1.5±0.1 1.6-1.8	≤2000 2200-3500	2.5 2.6	5.6 5.6	20.3 15.9	125
29.72	2±0.1	≤2000	3.3	7.7	24.5	125
32	2±0.1	≤2000	3.3	7.7	26.1	125
35	2±0.1 2.1-2.4	≤2000 2200-4200	3.8 3.8	7.6 7.6	29.1 24.9	125
38.1	2±0.1	≤2000	3.3	7.7	32.8	125
40	2±0.1 2.1-2.4	≤2000 2200-4200	3.3 3.5	7.7 8.1	33.9 30.7	125
45	2.3±0.1	≤2000	3.6	8.8	37.9	125
50.8	2.5±0.1 2.6-2.9	≤2000 2200-4200 2600-3500	3.6 3.8 3.3	8.8 8.6 7	43.3 41.5 41.5	125
55	2.5±0.1 2.5-2.9	≤2000 ≤4200	3.3 3.8	8.8 8.6	47.3 45.7	125
60	2.6-3.0	≤4200	3.8	8.6	49.8	125
63.5	2.7-3.1	≤4200	3.8	8.6	53.4	125
70	3.0-3.4	≤4200	5.2	10.1	59.9	125
76	3.5-4.1	≤4800	5.2	10.1	65.1	125
89	4-4.4	≤4200	5.2	10.1	77.7	125
99	4.5-4.8	≤3500	5.2	10.1	87.7	125

## 整流管芯片 DIODE CHIPS

### 标准:

- ◆每只芯片全部在T<sub>jm</sub>下测试，严格禁止抽检
- ◆产品参数一致性极佳

### Standard:

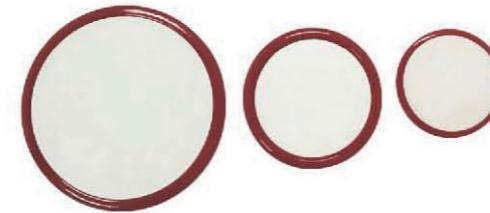
- ◆Every chip is tested at T<sub>jm</sub>, random inspection is strictly prohibited
- ◆Excellent consistency of the chips' parameters

### 特点:

- ◆通态压降低
- ◆具有很强的抗热疲劳能力
- ◆阴极铝层厚度10微米以上
- ◆台面双层保护

### Features:

- ◆Low forward voltage
- ◆Strong thermal fatigue resistance
- ◆The thickness of cathode aluminum layer is above 10μm
- ◆Double layer protections on mesa



芯片直径 Diameter	芯片厚度 Thickness	电压范围 Voltage	阴极外径 Cathode Outer Dia.	结温 T <sub>jm</sub>
(mm)	(mm)	(v)	(mm)	( C )
17	1.5±0.1	≤2600	12.5	150
23.3	1.95±0.1	≤2600	18.5	150
	2.15±0.1	4200-5500	16.5	150
24	1.5±0.1	≤2600	18.5	150
25.4	1.4-1.7	≤3500	19.5	150
29.72	1.95±0.1	≤2600	25	150
	1.9-2.3	2800-5500	23	150
32	1.9±0.1	≤2200	27.5	150
	2±0.1	2400-2600	26.3	150
35	1.8-2.1	≤3500	29	150
	2.2±0.1	3600-5000	27.5	150
36	2.1±0.1	≤2200	31	150
38.1	1.9±0.1	≤2200	34	150
40	1.9-2.2	≤3500	33.5	150
	2.2-2.5	3600-6500	31.5	150
45	2.3±0.1	≤3000	39.5	150
	2.5±0.1	3600-4500	37.5	150
50.8	2.4-2.7	≤4000	43.5	150
	2.8±0.1	4200-5000	41.5	150
55	2.4-2.8	≤4500	47.7	150
	2.8-3.1	5200-6500	44.5	150
63.5	2.6-3.0	≤4500	56.5	150
	3.0-3.3	5200-6500	54.5	150
70	2.9-3.1	≤3200	63.5	150
	3.2±0.1	3400-4500	62	150
76	3.4-3.8	≤4500	68.1	150
89	3.9-4.3	≤4500	80	150
99	4.4-4.8	≤4500	89.7	150

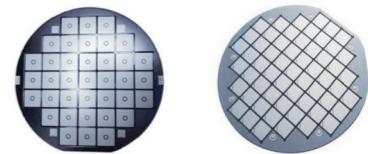
## 方形晶闸管芯片 SQUARE THYRISTOR CHIPS

### 特点:

- ◆通态压降低
- ◆Sipos、台面玻璃钝化工艺技术、多层金属化技术等

### Features:

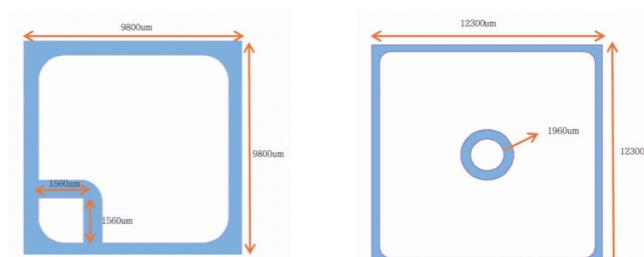
- ◆The on-state voltage drop is low
- ◆Sipos, glass passivation and multilayer metallization technology is applied



序号 No.	芯片尺寸 Size	表面金属 Surface Metal	门极 Gate Mode	电流 Current
1	250mil	多层金属	角门极Corner Gate	25A
2	300mil		角门极Corner Gate	45A
3	370mil		角门极Corner Gate	60A
4	480mil		中心门极Center Gate	110A
5	590mil		中心门极Center Gate	160A
6	710mil		中心门极Center Gate	200A

序号 No.	芯片尺寸 Size	长 Length (um)	宽 Width (um)	厚 Thickness (um)	门极形状 Gate Shape	门极尺寸 Gate Size (um)
1	250mil	1310	7000	6300	410	三角形Triangle
2	300mil		7600	7600	410	三角形Triangle
3	370mil		9800	9800	410	三角形Triangle
4	480mil		12300	12300	410	圆形Round
5	590mil		15200	15200	410	圆形 Round
6	710mil		17800	17800	410	圆形 Round

序号 No.	芯片尺寸 Size	V <sub>GТ</sub> V	I <sub>GТ</sub> mA	I <sub>H</sub> mA	I <sub>L</sub> mA	V <sub>TM</sub> V	I <sub>DRM/I<sub>RRM</sub></sub> (25°C) uA	I <sub>DRM/I<sub>RRM</sub></sub> (125°C) mA	V <sub>DRM/V<sub>RRM</sub></sub> V
1	250mil	0.7~1.5	20~60	40~120	60~150	1.8	10	8	1600
2	300mil	0.7~1.5	10~80	40~120	60~150	1.8	50	10	1600
3	370mil	0.6~1.3	10~80	40~100	50~120	1.8	50	10	1600
4	480mil	0.8~2.0	20~120	60~250	300	1.8	100	20	1600
5	590mil	0.8~2.0	20~150	60~250	350	1.8	100	30	1600
6	710mil	0.8~2.0	20~150	60~250	350	1.8	100	30	1600

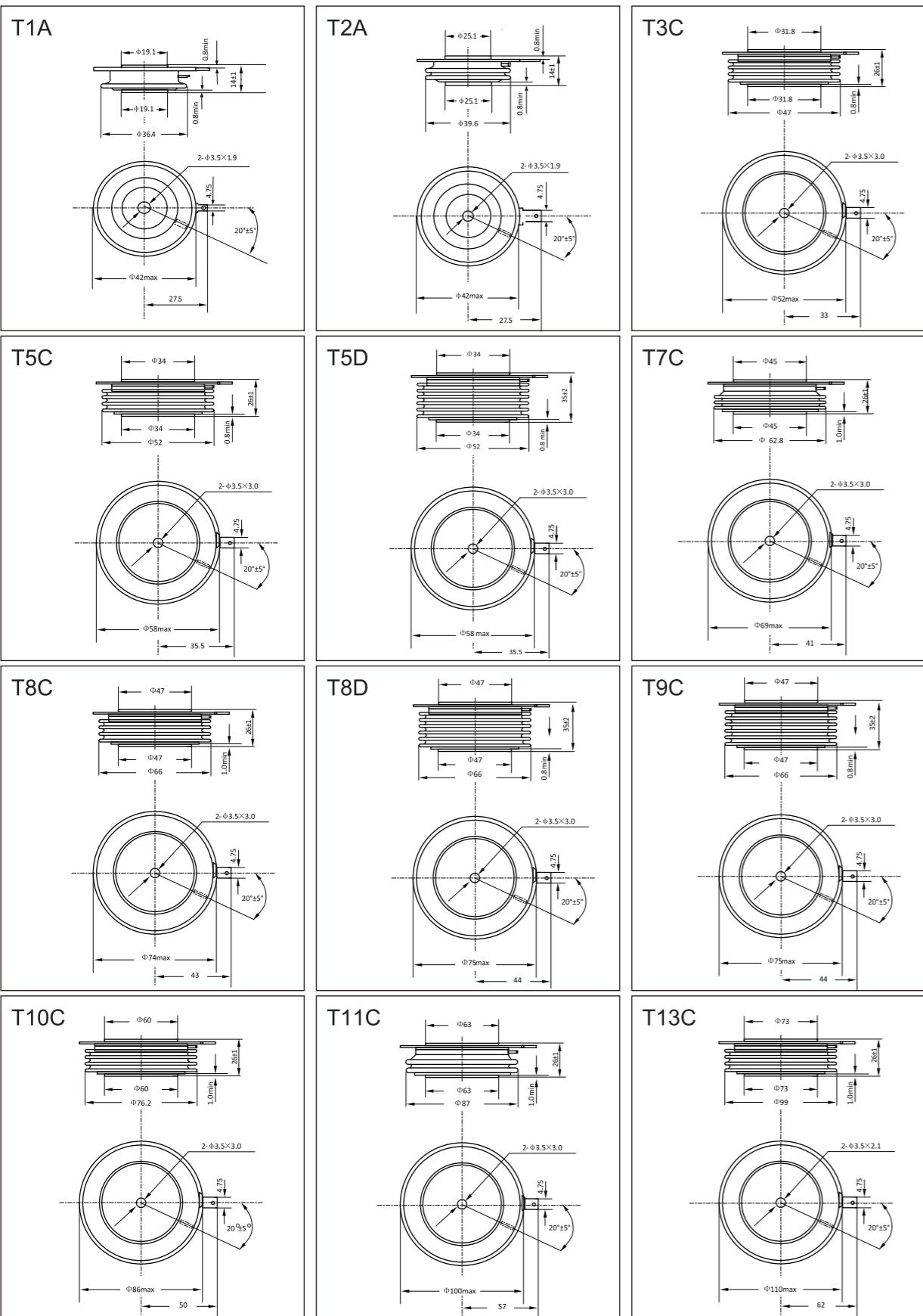




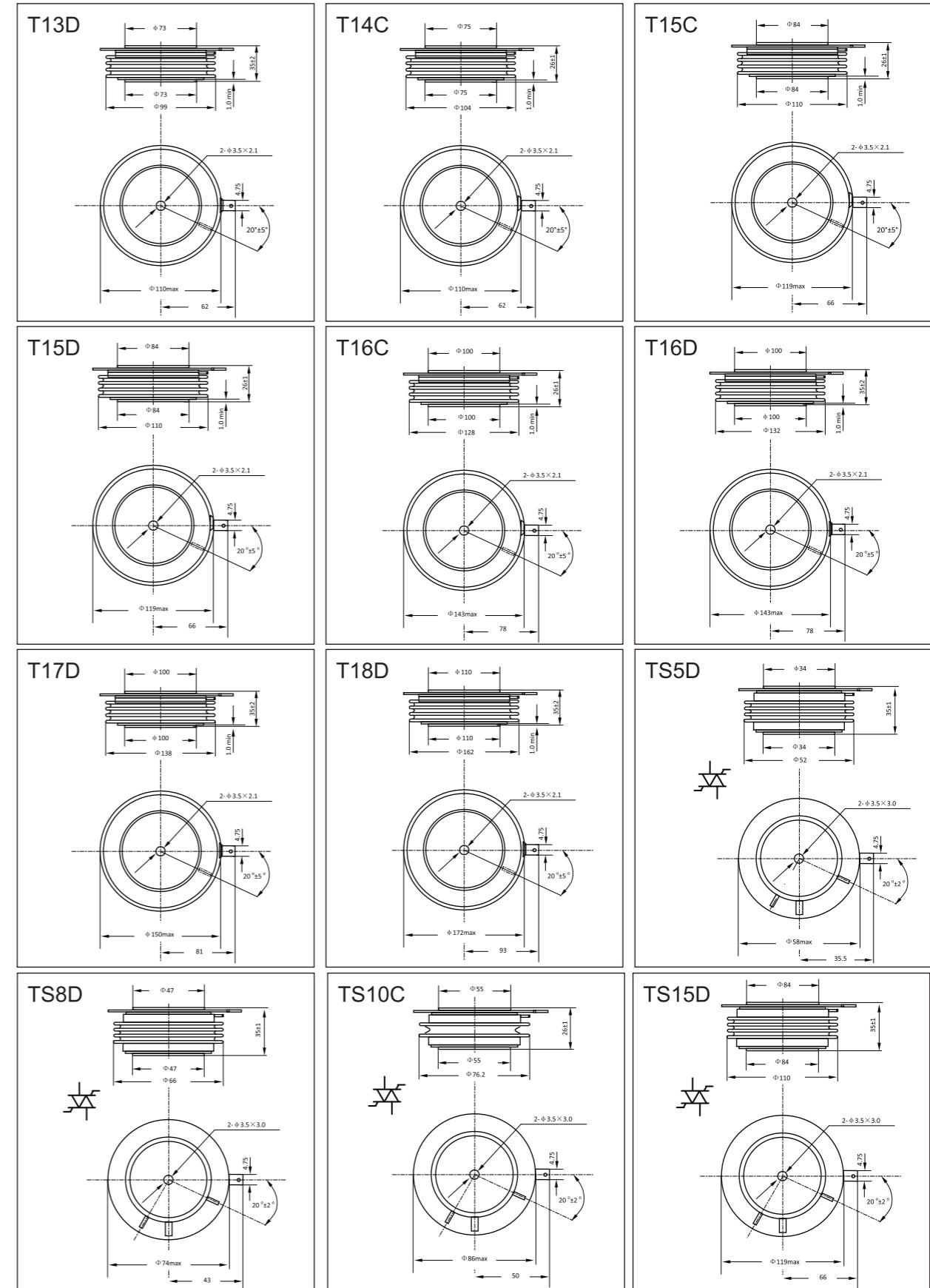




晶闸管外形图  
OUTLINE OF CAPSULE TYPE THYRISTOR



晶闸管外形图  
OUTLINE OF CAPSULE TYPE THYRISTOR



注：门极阴极引线长 400mm，未标注数量单位的统一为毫米 Remark: The standard length of gate and cathode leads is 400mm, All dimensions shown in mm unless stated otherwise





## 快恢复整流管 FAST RECOVERY DIODE

**特点:**

- 扩散结
- 短恢复时间
- 很小的反向恢复电流
- 快速软恢复特性

**应用领域:**

- 电机控制和驱动
- 感应加热
- UPS电源
- 斩波器
- 焊接设备

**Features:**

- Diffused junction
- Short recovery time
- Small reverse recovery current
- Fast soft recovery characteristics

**Applications:**

- Motor control and drive
- Induction heating
- UPS Power supply
- Chopper
- Welding equipment

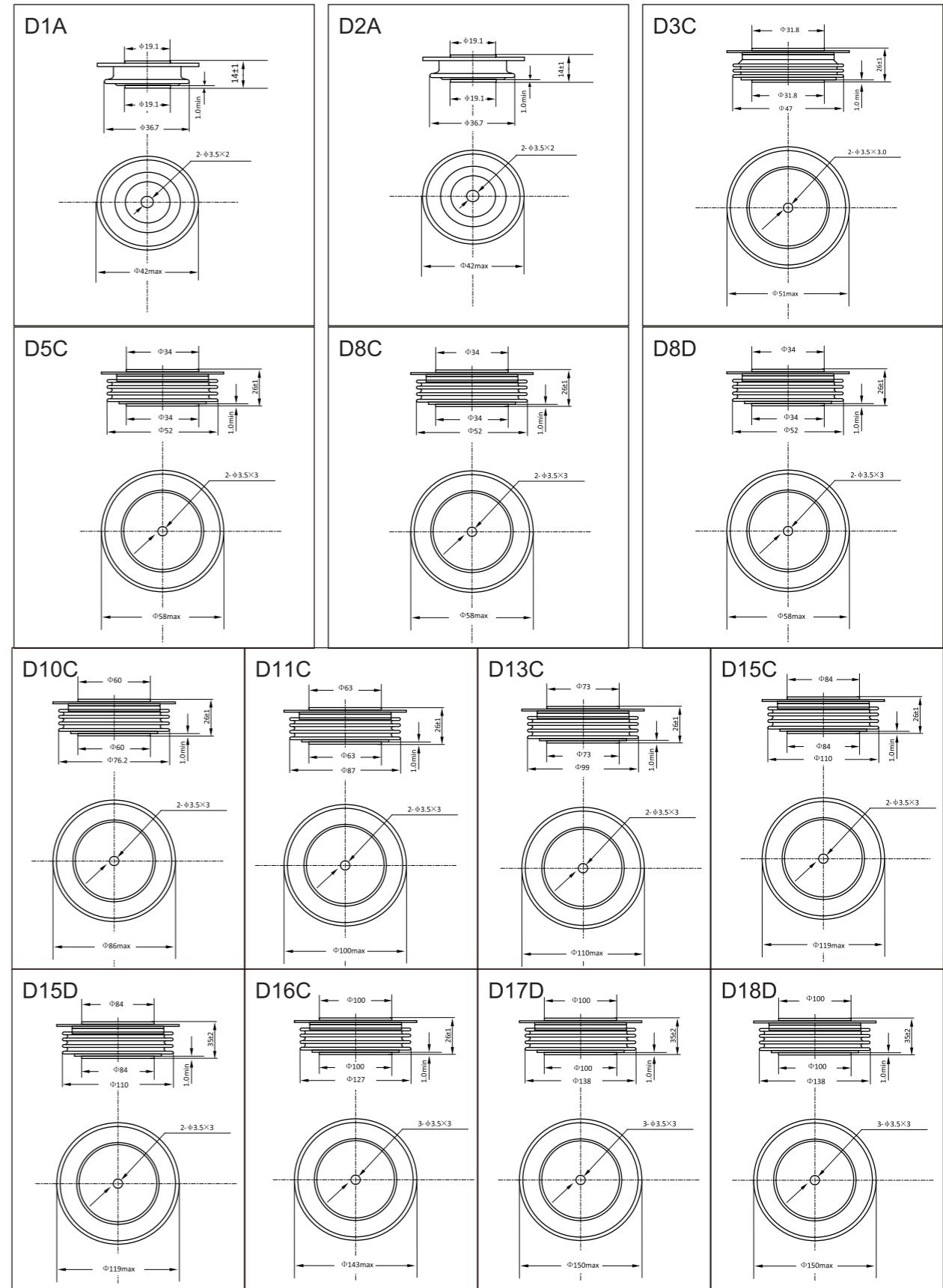


型号	I <sub>F(AV)</sub>	T <sub>c</sub>	V <sub>RRM</sub>	I <sub>FSM</sub> @T <sub>JM</sub> &10ms	I <sup>2</sup> t	V <sub>FM</sub> @I <sub>t</sub> &T <sub>J</sub> =25°C		t <sub>rr</sub>	T <sub>Jm</sub>	R <sub>Jc</sub>	R <sub>C-S</sub>	F	m	外形
TYPE	A	C	V	A	A <sup>2</sup> s	V	A	μs	℃	C/W	C/W	KN	Kg	Outline
<b>电压至 1800V(Up to 1800V)</b>														
ZK300-**	300	70	1000~1800	4500	1.01×10 <sup>5</sup>	2.3	900	4	125	0.08	0.02	4	0.06	D1A
ZK400-**	400	70	1000~1800	6000	1.8×10 <sup>5</sup>	2.3	1200	4	125	0.054	0.01	10	0.08	D2A
ZK500-**	500	70	1000~1800	7500	2.8×10 <sup>5</sup>	2.3	1500	5	125	0.045	0.01	13	0.2	D3C
ZK800-**	800	70	1000~1800	9600	4.6×10 <sup>5</sup>	2.3	2400	5	125	0.039	0.008	15	0.26	D5C
ZK1200-**	1200	70	1000~1800	18000	1.62×10 <sup>6</sup>	2.2	3000	6	125	0.022	0.005	25	0.46	D8C
ZK1500-**	1500	70	1000~1800	21000	2.2×10 <sup>6</sup>	2.2	3000	6	125	0.016	0.0045	28	0.65	D10C
ZK2000-**	2000	70	1000~1800	28000	3.9×10 <sup>6</sup>	2.2	3000	6	125	0.0125	0.004	33	0.85	D11C
ZK3000-**	3000	70	1000~1800	45000	1.0×10 <sup>7</sup>	2.0	3000	6	125	0.01	0.003	35	1.1	D13C
<b>电压至 3000V(Up to 3000V)</b>														
ZK200-**	200	70	2000~3000	3000	4.5×10 <sup>4</sup>	2.4	600	6	125	0.08	0.02	4	0.06	D1A
ZK300-**	300	70	2000~3000	4800	1.15×10 <sup>5</sup>	2.4	1200	6	125	0.054	0.01	10	0.08	D2A
ZK400-**	400	70	2000~3000	6400	2.0×10 <sup>5</sup>	2.4	1200	8	125	0.045	0.01	13	0.2	D3C
ZK500-**	500	70	2000~3000	9000	4.05×10 <sup>5</sup>	2.6	1500	8	125	0.039	0.008	15	0.26	D5C
ZK1000-**	1000	70	2000~3000	15000	1.12×10 <sup>6</sup>	2.6	3000	8	125	0.022	0.005	25	0.46	D8C
ZK1500-**	1500	70	2000~3000	22500	2.5×10 <sup>6</sup>	2.6	3000	8	125	0.015	0.0045	30	0.72	D10C
ZK2000-**	2000	70	2000~3000	30000	4.5×10 <sup>6</sup>	2.6	3000	8	125	0.0125	0.004	33	0.85	D11C
ZK2500-**	2500	70	2000~3000	38000	7.2×10 <sup>6</sup>	2.4	3000	8	125	0.01	0.003	35	1.1	D13C
<b>电压至 4500V(Up to 4500V)</b>														
ZK500-**	500	70	4000~4500	7500	4×10 <sup>5</sup>	4.0	1000	8	125	0.039	0.008	15	0.26	D5C
ZK1000-**	1000	70	4000~4500	15000	1.1×10 <sup>6</sup>	3.5	1500	9	125	0.022	0.005	25	0.46	D8C
ZK2200-**	2200	70	4000~4500	33000	4.5×10 <sup>6</sup>	3.0	3000	12	125	0.01	0.003	35	1.1	D13C

## YA系列软快恢复整流管 YA SERIES SOFT FAST RECOVERY DIODE

型号	I <sub>F(AV)</sub>	T <sub>c</sub>	V <sub>RRM</sub>	I <sub>FSM</sub> @T <sub>JM</sub> &10ms	I <sup>2</sup> t	V <sub>TM</sub> @I <sub>t</sub> &T <sub>J</sub> =25°C		t <sub>rr</sub>	T <sub>Jm</sub>	R <sub>Jc</sub>	R <sub>C-S</sub>	F	m	外形
TYPE	A	C	V	A	A <sup>2</sup> s	V	A	μs	℃	C/W	C/W	KN	Kg	Outline
<b>电压至 2000V(Up to 2000V)</b>														
YA696	1000	70	1500~2000	14000	9.8×10 <sup>5</sup>	1.9	1000	5	150	0.039	0.008	15	0.26	D5C
<b>电压至 2500V(Up to 2500V)</b>														
YA796	925	70	1500~2500	13800	9.5×10 <sup>5</sup>	1.75	1000	3.5	125	0.022	0.005	25	0.46	D8C

整流管外形图  
OUTLINE OF DIODE









晶闸管 / 整流管混合模块  
THYRISTOR/DIODE MODULE

型号 TYPE	IT(AV) @85°C A	VDRM/VRRM V mA	IDRM/IRRM		VTM/VFM		IGT 25°C Max	VGT 25°C Max	IH mA	dv/dt VD=12V 25°C Min	Viso 50Hz,RMS 2mA, 1min V/μS	模块外形 Outline
			25°C	125°C	25°C	25°C						
			Max	Max	Max	I <sub>TM</sub>						
<b>MFC/MFK/MFA/MFX 1200-2000V 水冷(Water cooling)</b>												
MF*200-**	200	1200-2000	1	20	1.5/1.3	600	30-100	0.8-2.2	20-120	1000	2500	M4-53-S
MF*250-**	250	1200-2000	1	20	1.5/1.3	750	30-100	0.8-2.2	20-120	1000	2500	M4-53-S
MF*300-**	300	1200-2000	1	20	1.5/1.3	900	30-100	0.8-2.2	20-120	1000	2500	M4-53-S
MF*350-**	350	1200-2000	1	35	1.5/1.3	1050	30-100	0.8-2.2	20-120	1000	2500	M4-53-S
MF*500-**	500	1200-2000	1	45	1.5/1.3	1500	30-100	0.8-2.2	20-120	1000	2500	M4-63-S
MF*600-**	600	1200-2000	1	55	1.5/1.3	1800	30-100	0.8-2.2	20-120	1000	2500	M4-66-S
MF*800-**	800	1200-2000	2	65	1.6/1.3	2400	30-100	0.8-2.2	20-120	1000	2500	M4-76-S

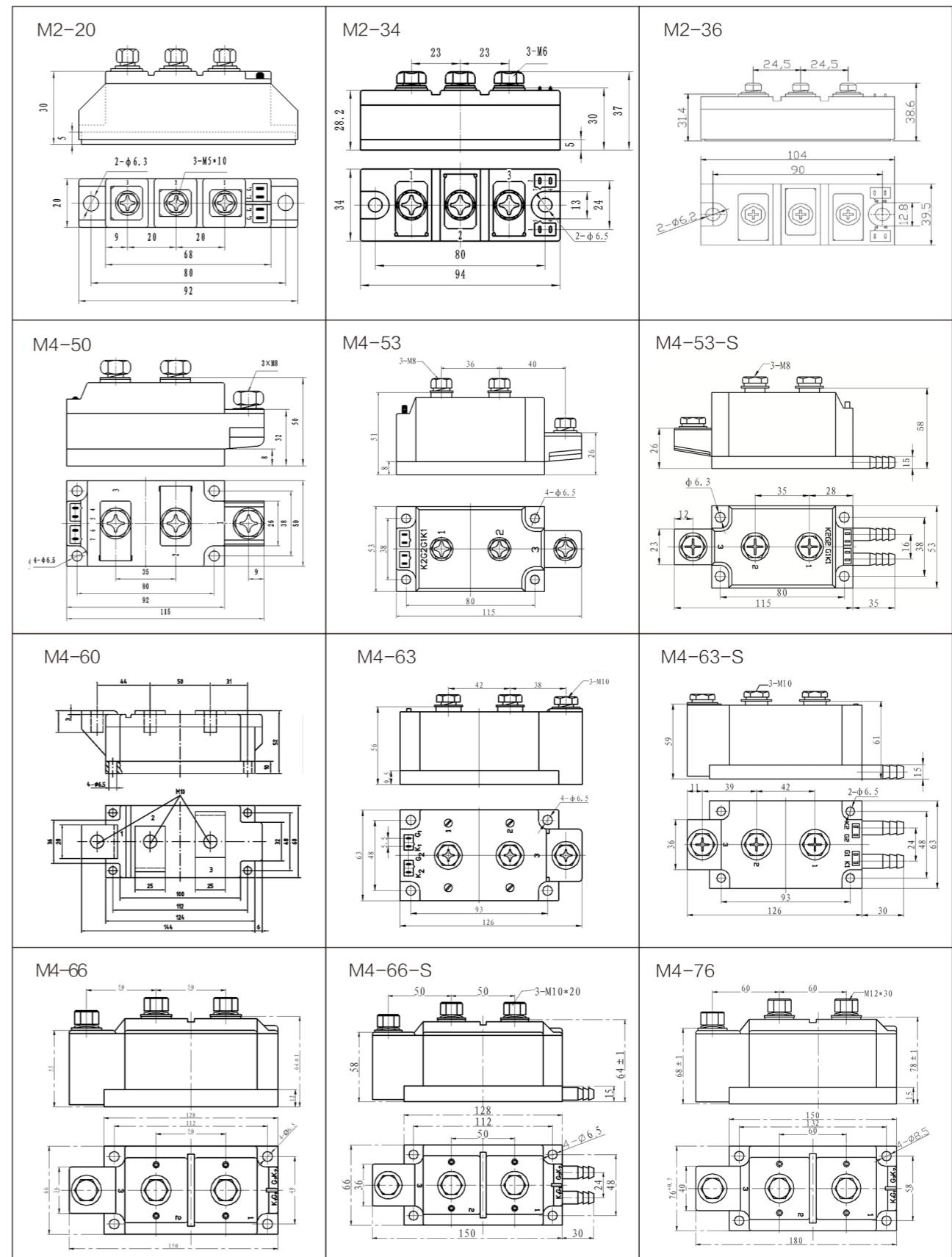
备注：\*代表连接方式 \*\*代表模块电压

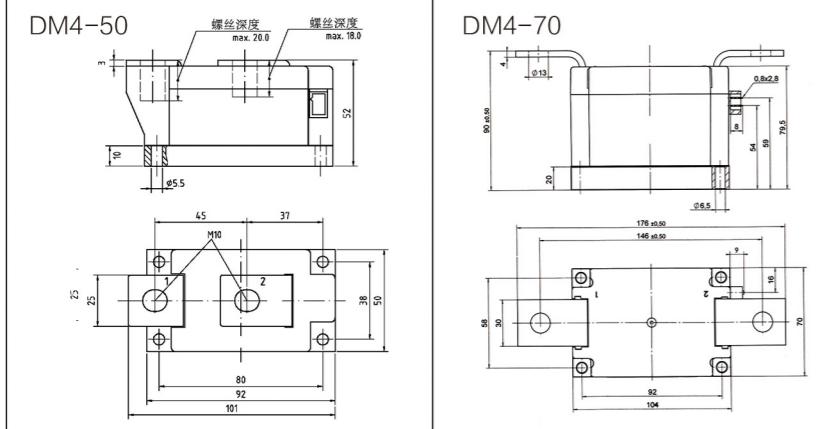
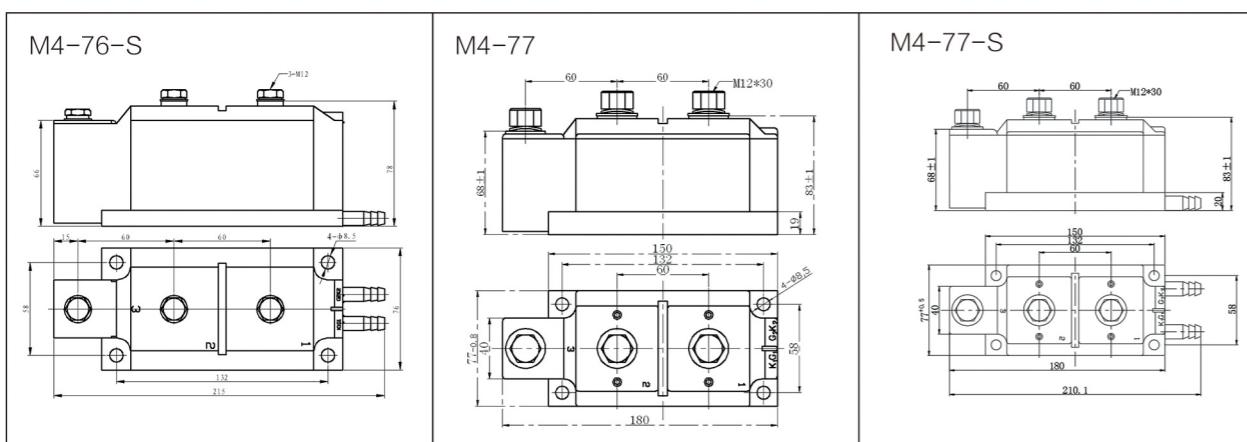
Ypack™ 系列高可靠性晶闸管 / 整流管模块  
YPACK™ HIGH RELIABILITY THYRISTOR/DIODE MODULE

型号 TYPE	IT(AV) @85°C A	VDRM/VRRM V mA	IDRM/IRRM		VTM/VFM		IGT 25°C Max	VGT 25°C Max	IH mA	dv/dt VD=12V 25°C Min	Viso 50Hz,RMS 2mA, 1min V/μS	模块外形 Outline
			25°C	125°C	25°C	25°C						
			Max	Max	Max	I <sub>TM</sub>						
<b>Ypack™ 系列晶闸管/整流管模块 Ypack™ High Reliability Thyristor/Diode Module</b>												
TD162-**	162	1200-2000	1	20	1.45/1.30	480	30-100	0.8-2.2	20-120	1000	2500	M2-34
TD275-**	275	1200-2000	1	20	1.55/1.30	750	30-100	0.8-2.2	20-120	1000	2500	M4-50
TD330-**	330	1200-2000	1	35	1.6/1.30	900	30-100	0.8-2.2	20-120	1000	2500	M4-60
TD570-**	570	1200-2000	2	65	1.6/1.30	1500	30-100	0.8-2.2	20-120	1000	2500	M4-60

备注：\*代表连接方式 \*\*代表模块电压

模块外形图  
OUTLINE OF POWER MODULE



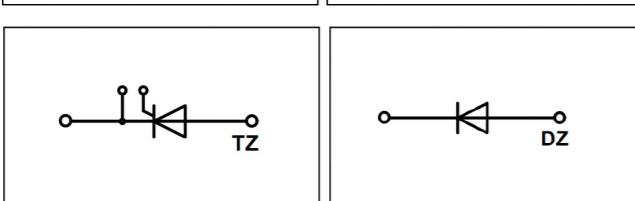
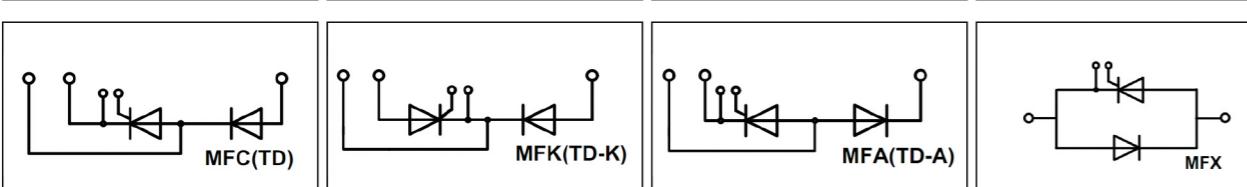
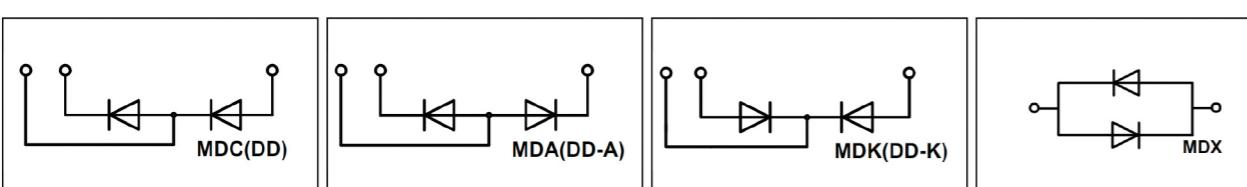
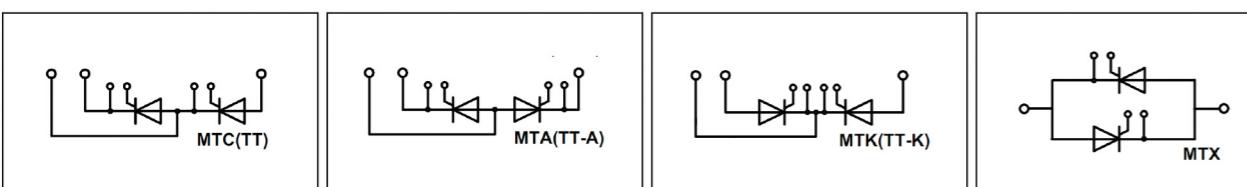


注:

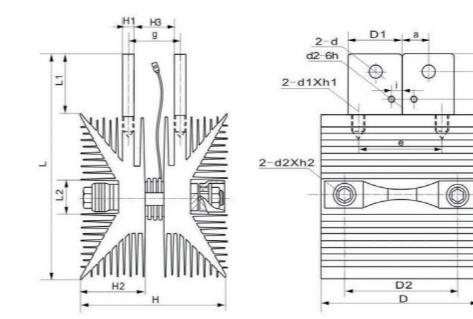
- 门极阴极引线长 300mm
- 未标注数量单位的统一为毫米

Remark:

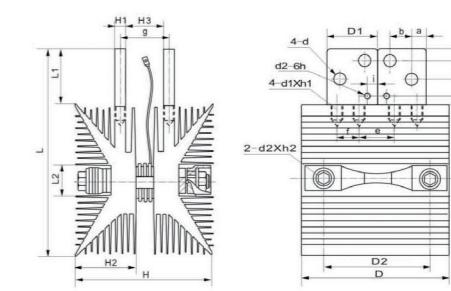
- The standard length of gate and cathode leads is 300mm
- All dimensions shown in mm unless stated otherwise



## SF 系列风冷散热器 AIR COOLING HEATSINKS OF SF SERIES



SF11, SF12, SF13 forced air cooling heatsink (with disc device)



SF14, SF15, SF16, SF17, SF17A, SF18, SF18A forced air cooling heatsink (with disc device)

型号 TYPE	台面直径 Contact Dia.			外形尺寸 Outline Dimensions			外形尺寸 Outline Dimensions			安装尺寸 Mounting Dimension				
	A	L	D	H	L1	D1	H1	L2	D2	H2	H3	d	d2*h2	
SF11	45	170	110	125	60	40	8	33	80	15	22	2hole φ13	M10*120	
SF12	50	200	110	125	60	40	8	33	80	15	22	2hole φ13	M10*120	
SF13	50	220	120	130	60	40	8	33	90	15	45	2hole φ13	M10*120	
SF14	65	250	140	145	80	50	10	38	105	15	45	4hole φ11	M12*140	
SF15	65	280	140	165	80	60	12	38	105	15	45	4hole φ11	M12*150	
SF16	80	280	180	200	80	60	12	34	130	15	66	4hole φ11	M12*180	
SF17	80	300	200	215	80	60	12	34	140	15	73	4hole φ11	M12*180	
SF17A	80	300	200	225	80	60	12	34	140	24	82	4hole φ11	M12*180	

型号 TYPE	安装尺寸 Mounting Dimension								热阻 Thermo Resistance		重量 Weight	
	a	b	c	e	f	g	i	j	C/W		kg	
SF11	45	170	110	125	60	40	8	33		≤0.120		2
SF12	50	200	110	125	60	40	8	33		≤0.090		2.6
SF13	50	220	120	130	60	40	8	33		≤0.071		3.5
SF14	65	250	140	145	80	50	10	38		≤0.056		4.9
SF15	65	280	140	165	80	60	12	38		≤0.048		6
SF16	80	280	180	200	80	60	12	34		≤0.037		9.5
SF17	80	300	200	215	80	60	12	34		≤0.030		13.5
SF17A	80	300	200	225	80	60	12	34		≤0.030		13.5

注:

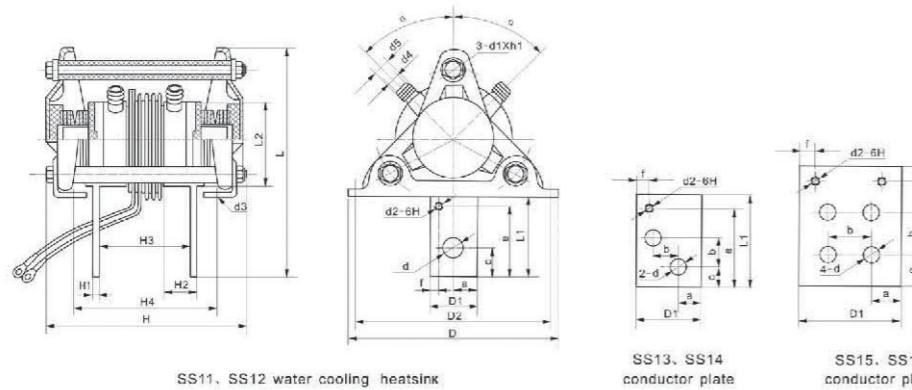
以上均为通用型号，如有特殊定制设计需要，请联系技术支持。

Remark:

All above mentioned are general purpose only, if any special customization required, please contact for technical support.



## SS 系列水冷散热器 WATER COOLING HEATSINKS OF SS SERIES



型号 TYPE	台面直径 Contact Dia.	外形尺寸 Outline Dimensions			导电排尺寸 Conducting Bar			安装尺寸 Mounting Dimension							
		mm	L	D	H	L1	D1	H1	D2	H2	H3	H3	d	d1xh1	d2
SS11	40	140	135	146	53	30	4	33	22	80	15	2hole φ13	M8x140	M3	
SS12	50	190	160	152	78	40	5	33	22	80	15	2hole φ13	M8x145	M3	
SS13	65	190	160	152	78	50	6	33	45	90	15	2hole φ13	M12x145	M4	
SS14	80	220	195	188	85	55	6	38	45	105	15	4hole φ11	M12x160 M12x180	M4	
SS15	100	235	195	190	95	80	8	38	45	154±4	15	4hole φ13	M12x180	M4	
SS16	108	288	260	230	105	80	8	34	66	154±4	15	4hole φ13	M12x220	M4	

型号 TYPE	安装尺寸 Mounting Dimension											热阻 Thermo Resistance	散热器重量 Weight
	d3	d4	d4	a	b	c	e	f	g	a	k/W		
SS11	2 holeΦ10x14	13	9	-	-	20	35	6	-	45°	≤0.026	0.7	
SS12	2 holeΦ12x14	13	9	-	-	20	60	8	-	45°	≤0.018	1.1	
SS13	2 holeΦ10x15	13	9	15	20	20	60	8	20	45°	≤0.015	1.6	
SS14	2 holeΦ12x20	13	9	18	20	20	65	10	20	45°	≤0.013	2.2	
SS15	2 holeΦ10x20	16	12	20	40	20	90	10	40	45°	≤0.010	4.4	
SS16	2 holeΦ11x25	16	12	20	40	20	90	10	40	45°	≤0.008	5	



## 功率组件 POWER ASSEMBLIES

直接采用功率组件进行设备设计和制造，具有选型简单、可靠性高、综合成本低、安装使用方便、外形美观、开发速度快等一系列优点。  
目前在国际上较通用，并且已形成标准化的，以晶闸管和二极管为核心的组件品种有：

单相整流桥系列：包括单相全控、半控和整流桥；

三相全桥系列：包括三相全控整流、三相半控整流、三相整流桥；

六相桥系列：包括六相可控和不可控整流桥；

交流开关系列：包括单相和三相交流开关；

以及其他特殊电联结形式的产品。

从组件的冷却方式上看，有铝型材及热管的强迫风冷、自然冷却、水冷等不同的形式。

从组件的功能上分，有具备基本电联结形式的功率组件；有在此基础上进一步配置阻容吸收、温度保护、通用或特殊控制功能的组件。

我们公司可提供各种类型的晶闸管、二极管及其模块产品的功率组件，可广泛应用于整流、逆变、开关、控制等各种领域中。

专业的事情请交给专业的我们！

